

Form PTO 1449  
(Modified)U.S. DEPARTMENT OF COMMERCE  
PATENT AND TRADEMARK OFFICE

ATTY DOCKET NO.

218447US2TTC

SERIAL NO.

NEW APPLICATION

## LIST OF REFERENCES CITED BY APPLICANT

APPLICANT

Akira GODA, et al.

FILING DATE

HEREWITH

GROUP

## U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						
	AL						
	AM						
	AN						

## FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION	
					YES	NO
<i>m</i>	AO	2000-286349	10/13/00	JAPAN		X
	AP	8-17948	01/19/96	JAPAN		X
	AQ	10-256399	09/25/98	JAPAN		X
	AR	4-12573	01/17/92	JAPAN		X
	AS					
	AT					
	AU					
	AV					

## OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)

<i>m</i>	AW	S. ARITOME, et al., "A. 0.67 $\mu$ m <sup>2</sup> Self-Aligned Shallow Trench Isolation Cell(SA-STI Cell) For 3v-only 256Mbit NAND EEPROMs", IEDM TECH. DIGEST, 1994, pgs. 3.6.1-3.6.4
	AX	
	AY	
	AZ	

☐ Additional References sheet(s) attached

Examiner

Date Considered

NOV 5 2001

\*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

JCS23 U.S. PTO

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01/30/02